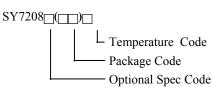


High Efficiency 1MHz, 600mA Step Up Regulator

General Description

The SY7208C is a high efficiency boost regulator targeted for general step-up applications.

Ordering Information



Ordering Number	Package type	Note
SY7208CABC	SOT23-6	

Features

- Wide input range: 3-25V bias input, 25Vout max
- 1MHz switching frequency
- Minimum on time: 100ns typical
- Minimum off time: 100ns typical
- Low R_{DS(ON)}: 150mΩ
- RoHS Compliant and Halogen Free
- Accurate Reference: 0.6V_{REF}
- Compact package: SOT23-6

Applications

- WLED Drivers
- Networking car s powered from PCI or PCIexpress slots

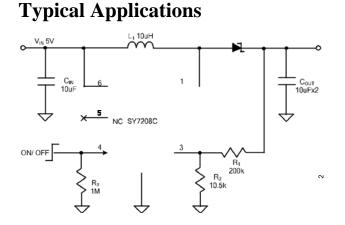


Figure 1. Schematic Diagram

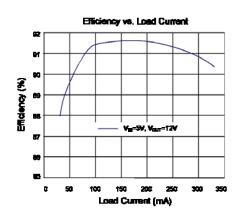
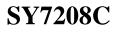
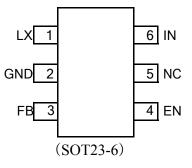


Figure 2. Efficiency vs Load Current





Pinout (top view)



Top Mark: JUxyz (Device code: JU, x=year code, y=week code, z= lot number code)

Pin Name	Pin Number	Pin Description	
IN	6	Input pin. Decouple this pin to GND pin with 1uF ceramic cap.	
GND	2	Ground pin	
LX	1	Inductor node. Connect an inductor between IN pin and LX pin.	
FB	3	Feedback pin. Connect a resistor R1 between V_{OUT} and FB, and a resistor R2 between FB and GND to program the output voltage: $V_{OUT}=0.6V*(R1/R2+1)$.	
EN	4	Enable control. High to turn on the part. Don't l eave it floated.	
NC	5	No connection.	

Absolute Maximum Ratings (Note 1)

LX, IN, EN	26V
All other pins	4V
Power Dissipation, PD @ TA = 25°C SOT23-6	0.6W
Package Thermal Resistance (Note 2)	
θ _{JA}	161°C/W
θ _{JC}	130°C/W
Junction Temperature Range	125°C
Lead Temperature (Soldering, 10 sec.)	260°C
Storage Temperature Range	65°C to 150°C

Recommended Operating Conditions (Note 3)

Input Voltage Supply	3V to 25V
Junction Temperature Range	
Ambient Temperature Range	-40°C to 85°C



Electrical Characteristics

(VIN = 5V, V_{OUT}=12V, I_{OUT}=100mA, T_A = 25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Input Voltage Range	V IN		3		25	V
Quiescent Current	l Q	V _{FB} =0.66V		100		μΑ
Shutdown Current	I SHDN	EN=0		1	5	μA
Low Side Main FET	Rds(on)			150		mΩ
RON						
Main FET Current	I LIM1		600			mA
Limit						
Switching Frequency	Fsw		0.8	1	1.2	MHz
Feedback Reference	V REF		0.588	0.6	0.612	V
Voltage						
IN UVLO Rising	V IN,UVLO				2.3	V
Threshold						
UVLO Hysteresis	U VLO,HYS			0.1		V
Thermal Shutdown	I SD			150		°C
Temperature						
EN Rising Threshold	V ENH		2			V
EN Falling Threshold	V ENL				0.4	V
EN Pin Input Current	I EN		0		100	nA

Note 1: Stresses beyond "Absolute Maximum Ratings" m y ca use permanent damage to the device. These are for stress ratings. Functional operation of the device at hese or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

Note 2: θ_{JA} is measured in the natural convection at $T_A = 25^{\circ}$ C on a low effective single layer thermal conductivity test board of JEDEC 51-3 thermal measurement standard. Test condition: Device mounted on 2" x 2" FR-4 substrate PCB, 2oz copper, with minimum rec mmended pad on top layer and thermal vias to bottom layer ground plane.

Note 3: The device is not guaranteed to function outside its operating conditions.

Note 4: IC could be start up in 2.7V.

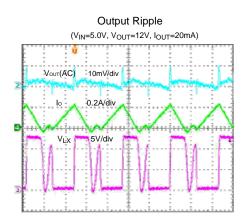


Load Transient Efficiency vs. Load Current (VIN=5V, VOUT=12V, ILOAD=0.05-0.3A) 92 91 Vout(AC) 0.1V/div 90 % 89 lò 0.1A/div ency 88 ₩=6V, Voun=12V 87 86 85 0 50 100 150 200 250 300 350 Time (100µs/div) ka Garriani (mesy LUA Startup from V_{IN} Shutdown from V_{IN} (VIN=5.0V, VOUT=12V, IOUT=0.3A) (Vm=5.0V, Vour=12V, Jour=0.3A) 2V/div V_{IN} Vout 5V/div Va 2Vide 2 Vour 5Vidiv 0.2A/div 0 3 b 0.2Akb 4 Time (1ms/div) Time (2ms/div) Startup from Enable Shutdown from Enable (VIN=5.0V, VOUT=12V, IOUT=0.3A) (VN=5.0V, Vout=12V, lout=0.3A) EN 2V/div 2V/div EN Vour 6VMW Vout 5V/div la. 0.2Aldv 0.2A/div lo Time (200µs/div) Time (100µs/div)

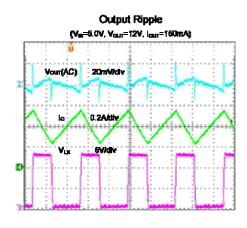
Typical Performance Characteristics

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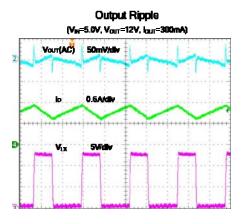




Time (400ns/div)



Time (400ns/div)



Time (400ns/div)



Applications Information

Because of the high integration in the SY7208C IC, the application circuit based on this regulator IC is rather simple. Only input capacitor C_{IN} , output capacitor C_{OUT} , inductor L and feedback resistors (R_1 and R_2) need to be selected for the targeted applications specifications.

Feedback resistor dividers R1 and R2:

Choose R_1 and R_2 to program the proper output voltage. To minimize the power consumption under light loads, it is desirable to choose large resistance values for both R_1 and R_2 . A value of between 10k and 1M is recommended for both resistors. If R_2 =120k is chosen, then R_1 can be calculated to be:

$$R_1 = \frac{(V_{OUT} - 0.6V) \times R_2}{0.6V}$$

Input capacitor CIN:

The ripple current through input capacitor is calculated as:

$$I_{\text{CIN_RMS}} = \frac{V_{\text{IN}} \cdot (V_{\text{OUT}} - V_{\text{IN}})}{2\sqrt{3} \cdot L \cdot F_{\text{SW}} \cdot V_{\text{OUT}}}$$

To minimize the potential noise problem, place a typical X7R or better grade ceramic capacitor really close to the IN and GND pins. Care should be taken o minimize the loop area formed by C_{IN} , and IN/GND pins.

Output capacitor Cour:

The output capacitor is selected to ha dle the output ripple noise requirements. Both steady state ripple and transient requirements must be taken into consideration when selecting this capacitor. For the best performance, it is recommended to use X7R or better grade ceramic capacitor with 25V rating and greater than 10uF capacitance.

Output inductor L:

There are several considerations in choosing this inductor.

1) Choose the inductance to provide the desired ripple current. It is suggested to choose the ripple current to be about 40% of the average input current. The inductance is calculated as:

$$L = \left(\frac{V_{IN}}{V_{OUT}}\right)^{2} \frac{(V_{OUT} - V_{IN})}{F_{SW} \times I_{OUT, MAX} \times 40\%}$$

where F_{SW} is the switching frequency and $I_{OUT,MAX}$ is the maximum load current.

The SY7208C regulator IC is quite tolerant of different ripple current amplitude. Consequently, the final choice of inductance can be slightly off the calculation value without significantly impacting the performance.

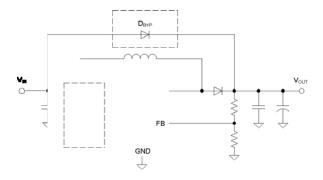
2) The saturation current rating of the inductor must be selected to be greater than the peak inductor current under full load conditions.

$$I_{\text{SAT, MIN}} > \left| \frac{V_{\text{OUT}}}{V_{\text{IN}}} \right| \qquad \times I_{\text{OUT, MAX}} + \left| \frac{V_{\text{IN}}}{V_{\text{OUT}}} \right|^2 \frac{(V_{\text{OUT}} - V_{\text{IN}})}{2 \times F_{\text{SW}} \times L}$$

3) The DCR of the inductor and the core loss at the switching frequency must be low enough to achi ve the desired efficiency requirement. It is desirable to choose an inductor with DCR<50mohm to achieve a good overall efficiency.

Applications with Large Bulk Capacitance

In applications with large bulk capacitance on the output, a very high inrush current can be seen flow through the inductor during power on. To avoid this inrush current flow into the IC and cause any unexpected damage, a Zener diode connected from power input to the output or an RC delay circuit added on EN pin of the IC can be used. Refer to the circuit below.



Layout Design:

The layout design of SY7208C regulator is relatively simple. For the best efficiency and minimum noise



problems, we should place the following components close to the IC: C_{IN} , L, R_1 and R_2 .

1) It is desirable to maximize the PCB copper area connecting to GND pin to achieve the best thermal and noise performance. If the board space allowed, a ground plane is highly desirable.

2) C_{IN} must be close to Pins IN and GND. The loop area formed by C_{IN} and GND must be minimized.

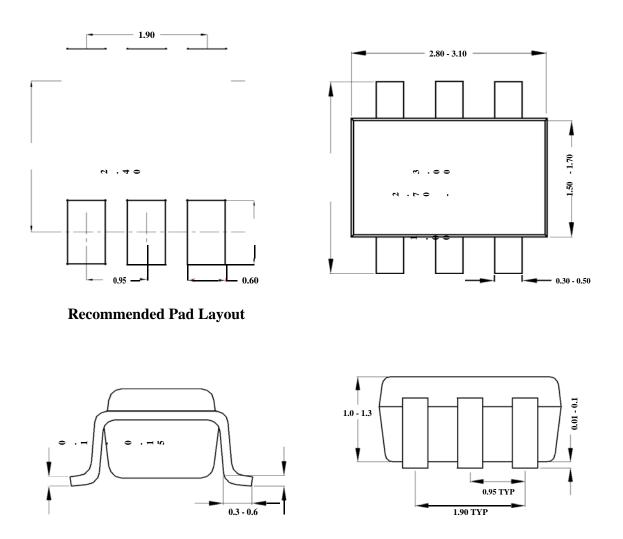
3) The PCB copper area associated with LX pin must be minimized to avoid the potential noise problem.

4) The components R_1 and R_2 , and the trace connecting to the FB pin must NOT be adjacent to the LX net on the PCB layout to avoid the noise problem.

5) If the system chip interfacing with the EN pin has a high impedance state at shutdown mode and the IN pin is connected directly to a power source such as a Li-Ion battery, it is desirable to add a pull down 1Mohm resistor between the EN and GND pins to prevent the noise from falsely turning on the regulator at shutdown mode.







Notes: All dimensions are in millimeters. All dimensions don't include mold flash & metal burr.

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